# NSN 5962-01-370-4949

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### **Body Length:** 1.290 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 1.02 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** W/buffered output and w/enable and w/active pull-up and 3-state output and high impedance and programmed and schottky and bipolar **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Criticality Code Justification:** Feat **Case Outline Source And Designator:** D-3 mil-m-38510 **Current Rating Per Characteristic:** 185.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Product Name:** Czd-3 Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 100.00 nanoseconds access Memory Device Type: Prom **Special Features:** Nuclear hardness critical item **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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#### Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

Fiig:

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